

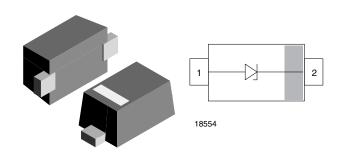




# **Small Signal Schottky Diode**

#### Features

- This diode features very low turn-on voltage and fast switching.
- This device is protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
  **RoHS**
- Space saving SOD-523 package
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



#### **Mechanical Data**

Case: SOD-523

#### Molding Compound Flammability Rating:

UL 94 V-0

**Terminals:** High temperature soldering guaranteed: 260 °C/10 s at terminals

Weight: approx. 1.6 mg

# Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

#### **Parts Table**

Part	Ordering code	Marking	Remarks	
BAS40-02V	BAS40-02V-GS18 or BAS40-02V-GS08	W	Tape and Reel	

COMPLIANT

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V <sub>RRM</sub>	40	V
Forward continuous current		١ <sub>F</sub>	200	mA
Surge forward current	t <sub>p</sub> < 1 s	I <sub>FSM</sub>	600	mA
Power dissipation		P <sub>tot</sub>	200	mW

#### **Thermal Characteristics**

 $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Junction soldering point		R <sub>thJS</sub>	100	K/W	
Junction temperature		Tj	125	°C	
Storage temperature range		T <sub>stg</sub>	- 55 to +150	°C	

# **Vishay Semiconductors**

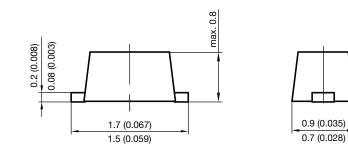


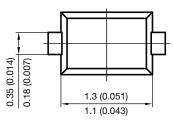
### **Electrical Characteristics**

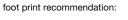
T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	$I_{R} = 10 \ \mu A \ (pulsed)$	V <sub>(BR)</sub>	40			V
Leakage current	Pulse test V_R = 30 V, t_p < 300 $\mu$ s	I <sub>R</sub>		20	100	nA
Forward voltage	Pulse test t <sub>p</sub> < 300 μs, I <sub>F</sub> = 1 mA	V <sub>F</sub>			380	mV
	Pulse test t <sub>p</sub> < 300 μs, I <sub>F</sub> = 40 mA,	V <sub>F</sub>			1000	mV
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz	CD		4	5	pF
Reverse recovery time	$I_{F} = 10 \text{ mA}, I_{R} = 10 \text{ mA},$ $I_{rr} = 1 \text{ mA}, R_{L} = 100 \Omega$	t <sub>rr</sub>			5	ns

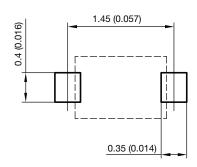
### Package Dimensions in millimeters (inches): SOD-523







0.7 (0.028) 0.5 (0.020)



Document no.: S8-V-3880.02-001 (4) Rev. g - Date: 13.April 2010 16864



Vishay

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